

## PATENT ASSIGNMENT COVER SHEET

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<b>SUBMISSION TYPE:</b>	NEW ASSIGNMENT
<b>NATURE OF CONVEYANCE:</b>	ASSIGNMENT
<b>CONVEYING PARTY DATA</b>	
<b>Name</b>	<b>Execution Date</b>
XIAOBO SHI	01/23/2020
JOSEPH D. ROSE	01/22/2020
HONGJUN ZHOU	01/27/2020
KRISHNA P. MURELLA	01/22/2020
MARK LEONARD O'NEILL	01/23/2020
<b>RECEIVING PARTY DATA</b>	
<b>Name:</b>	VERSUM MATERIALS US, LLC
<b>Street Address:</b>	8555 SOUTH RIVER PARKWAY
<b>Internal Address:</b>	PATENT DEPT.
<b>City:</b>	TEMPE
<b>State/Country:</b>	ARIZONA
<b>Postal Code:</b>	85284
<b>PROPERTY NUMBERS Total: 1</b>	
<b>Property Type</b>	<b>Number</b>
Application Number:	16711818
<b>CORRESPONDENCE DATA</b>	
<b>Fax Number:</b>	(610)862-9626
<i>Correspondence will be sent to the e-mail address first; if that is unsuccessful, it will be sent using a fax number, if provided; if that is unsuccessful, it will be sent via US Mail.</i>	
<b>Phone:</b>	484-246-5768
<b>Email:</b>	versumpatents@versummaterials.com
<b>Correspondent Name:</b>	LISA HOFFMANN
<b>Address Line 1:</b>	7350 TILGHMAN STREET, SUITE 104
<b>Address Line 2:</b>	PATENT DEPT.
<b>Address Line 4:</b>	ALLENTOWN, PENNSYLVANIA 18106-9000
<b>ATTORNEY DOCKET NUMBER:</b>	09296 USA
<b>NAME OF SUBMITTER:</b>	LINA YANG, PHD
<b>SIGNATURE:</b>	/Lina Yang, PhD/
<b>DATE SIGNED:</b>	01/29/2020
This document serves as an Oath/Declaration (37 CFR 1.63).	

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**Total Attachments: 2**

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**ASSIGNMENT & DECLARATION**

For value received, we, Xiaobo Shi, Joseph D. Rose, Hongjun Zhou, Krishna P. Murella and Mark Leonard O'Neill, hereby sell, assign, and transfer to **VERSUM MATERIALS US, LLC**, a corporation of the State of Delaware, having an office at 8555 South River Parkway, Tempe, AZ 85284, the entire right, title, and interest in and to the invention relating to

**Low Oxide Trench Dishing Shallow Trench Isolation Chemical Mechanical  
Planarization Polishing**

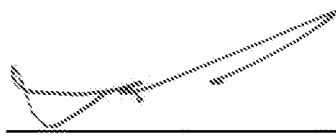
described in our application for Letters Patent of the United States (identified by Docket No. 09296 USA; and/or Appl. No. 16/711,818; filed on December 12, 2019), in and to all Letters Patent which may be issued upon said application, in and to any divisional or reissue applications based thereon, and in and to all Letters Patent upon said invention or improvements which may be granted in foreign countries. We hereby also assign and convey to said **VERSUM MATERIALS US, LLC**, all the rights accruing to us by virtue of the International Convention for the Protection of Industrial Property (Art. 4), including the right to apply for and to have patents issued in its own name.

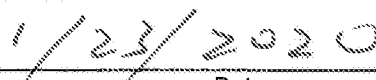
And we hereby authorize and request the Commissioner of Patents and Trademarks of the United States and the Officials of the Patent Offices of all other countries to issue the Letters Patent of their respective countries to said **VERSUM MATERIALS US, LLC**, as assignee of the entire right, title, and interest in and to the same.


And we hereby promise and agree to execute all papers and perform all acts necessary to secure to and vest in said **VERSUM MATERIALS US, LLC**, its successors and assigns, the rights conveyed as herein set forth.

And I hereby authorize the above-mentioned Assignee or its legal representative to insert in the instrument the application serial number of aforesaid application or any other information that may be necessary or desirable in order to comply with the rules of the United States Patent and Trademark Office.

And we hereby declare that the above-identified application was made or authorized to be made by me. I believe I am the original inventor or an original joint inventor of a claimed invention in the application. I hereby acknowledge that any willful false statement made in this declaration is punishable under 18 U.S.C. 1001 by fine or imprisonment of not more than five (5) years, or both.

  
\_\_\_\_\_(L.S.)  
Xiaobo Shi

  
\_\_\_\_\_  
Date

  
\_\_\_\_\_(L.S.)  
Joseph D. Rose

  
\_\_\_\_\_  
Date

Hongjun Zhou (L.S.)  
Hongjun Zhou

27 Jan 2020  
Date

Krishna P. Murella (L.S.)  
Krishna P. Murella

22 Jan 2020  
Date

Mark Leonard O'Neill (L.S.)  
Mark Leonard O'Neill

23 Jan 2020  
Date